

Refine Search

Search Results -

Terms	Documents
369/\$.CCLS. AND L2	0

Database:

US Pre-Grant Publication Full-Text Database
 US Patents Full-Text Database
 US OCR Full-Text Database
 EPO Abstracts Database
 JPO Abstracts Database
 Derwent World Patents Index
 IBM Technical Disclosure Bulletins

Search:

L7

Search History

DATE: Thursday, October 26, 2006
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Set Name Query

side by side

Hit Count Set Name

result set

DB=USPT,USOC,EPAB,JPAB; PLUR=YES; OP=OR

<u>L7</u>	369/\$.CCLS. AND L2	0	<u>L7</u>
<u>L6</u>	(SEMICONDUCTOR OR CHIP) AND L5	30	<u>L6</u>
<u>L5</u>	L3 AND L4	36	<u>L5</u>
<u>L4</u>	VOLTAGE ADJ10 DIFFEREN\$	170461	<u>L4</u>
<u>L3</u>	BIAS AND L2	38	<u>L3</u>
<u>L2</u>	LVDS AND L1	79	<u>L2</u>
<u>L1</u>	MOSFET	51454	<u>L1</u>

END OF SEARCH HISTORY